

## Reliability Data Sheet

### Description

The following cumulative test results have been obtained from testing performed Avago Technologies Malaysia in accordance with the latest revisions of MIL-STD-883. Avago Technologies tests parts at the absolute maximum rated conditions recommended for the device. The actual performance you obtain from Avago Technologies' parts depends on the electrical and environmental characteristics of your application but will probably be better than the performance outlined in Table 1.

### Failure Rate Prediction

The failure rate of semiconductor devices is determined by the junction temperature of the device. The relationship between ambient temperature and actual junction temperature is given by the following

$$T_J(^{\circ}\text{C}) = T_A(^{\circ}\text{C}) + \theta_{JA}P_{AVG}$$

where  $T_A$  = ambient temperature in  $^{\circ}\text{C}$

$\theta_{JA}$  = thermal resistance of junction-to-ambient in  $^{\circ}\text{C}/\text{Watt}$

$P_{AVG}$  = average power dissipated in Watt

The estimated MTBF and failure rate at temperatures lower than the actual stress temperature can be determined by using an Arrhenius model for temperature acceleration. Results of such calculations are shown in table 2 using an activation energy of 0.43eV (reference MIL-HDBK-217).

**Table 1. Life Tests Demonstrated Performance**

Test Name	Stress Test Conditions	Total Device Hours	Units Tested	Total Failed	Point Typical Performance	
					MTTF	Failure Rate (% /1 K Hours)
High Temperature Operating Life	Vcc=5.5V T <sub>A</sub> =85°C 1000hours	30,000	30	0	30,000	3.33
Low Temperature Operating Life	Vcc=5.5V T <sub>A</sub> =-40°C 1000hours	30,000	30	0	30,000	3.33
Wet High Temperature Operating Life	Vcc=5.5V T <sub>A</sub> =85°C Rh=85% 1000hours	386,000	386	0	386,000	0.26

**Table 2.**

Ambient Temperature (°C)	Junction Temperature (°C)	Point Typical Performance <sup>[1]</sup> in Time		Performance in Time <sup>[2]</sup> (90% Confidence)	
		MTTF <sup>(1)</sup>	Failure Rate (% / 1K Hours)	MTTF <sup>(2)</sup>	Failure Rate (% / 1K Hours)
85	94	837,000	0.12	104,000	0.96
75	84	1225,000	0.08	153,000	0.65
65	74	1832,000	0.05	229,000	0.44
55	64	2808,000	0.04	351,000	0.28
45	54	4416,000	0.02	552,000	0.18
35	44	7147,000	0.01	893,000	0.11
25	34	11936,000	0.008	1492,000	0.07

Notes:

- 1.The point typical MTTF (which represents 60% confidence level) is the total device hours divided by the number of failures. In the case of zero failures, one failure is assumed for this calculation.
- 2.The 90% Confidence MTTF represents the minimum level of reliability performance, which is expected, from 90% of all samples. This confidence interval is based on the statistics of the distribution of failures. The assumed distribution of failures is exponential. This particular distribution is commonly used in describing useful life failures. Refer to MIL-STD-690B for details on this methodology.
- 3.Failures are catastrophic or parametric. Catastrophic failures are open, short, no logic output, no dynamic parameters while parametric failures are failures to meet an electrical characteristic as specified in product catalog such as output voltage, duty or state errors.

### Example of Failure Rate Calculation

Assume a device operating 8 hours/day, 5 days/week. The utilization factor, given 168 hours/week is:  
 $(8 \text{ hours/day}) \times (5 \text{ days/week}) / (168 \text{ hours/week}) = 0.25$

The point failure rate per year (8760 hours) at 55 °C ambient temperature is:  
 $(0.04\% / 1K \text{ hours}) \times 0.25 \times (8760 \text{ hours/year}) = 0.09\% \text{ per year}$

Similarly, 90% confidence level failure rate per year at 55 °C:  
 $(0.28\% / 1K \text{ hours}) \times 0.25 \times (8760 \text{ hours/year}) = 0.61\% \text{ per year}$

**Table 3.Environmental Tests**

Test Name	Test Conditions	Units Tested	Units Failed
Temperature Cycle	-40°C to 85°C, 15 min. dwell 5 min. transfer.		
	100 cycles	770	0
	1000 cycles	30	0
Wet High Temperature Storage Life	T <sub>A</sub> =85°C Rh=85% 1000hours	30	0
Low Temperature Storage Life	T <sub>A</sub> =-40°C 1000hours	30	0

**Table 4. Electrical Tests**

<b>Test Name</b>	<b>Test Conditions</b>	<b>Units Tested</b>	<b>Units Failed</b>
ESD (Human Body Model)	JESD22-A114-A Up to 3kV applied to all pins versus ground	6	0
ESD (Machine Model)	JESD22-A114-A Up to 300V applied to all pins versus ground	6	0

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